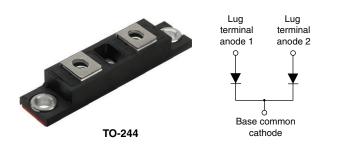
Vishay Semiconductors

High Performance Schottky Rectifier, 200 A



www.vishay.com

PRIMARY CHARACTERISTICS				
I _{F(AV)}	200 A			
V _R	100 V			
Package	TO-244			
Circuit configuration	Two diodes common cathode			

FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-203CNQ.. center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES				
I _{F(AV)}	Rectangular waveform	200	А			
V _{RRM}		100	V			
I _{FSM}	t _p = 5 μs sine	12 800	А			
V _F	100 A_{pk} , T_J = 125 °C (per leg)	0.70	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-203CNQ100PbF	UNITS		
Maximum DC reverse voltage	VR	100	V		
Maximum working peak reverse voltage	V _{RWM}	100	v		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER SYME		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average	per leg					100	
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T_C = 142 °C, rectangular waveform		200	A	
Maximum peak one cycle non-repetitive surge current per leg			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	12 800	A	
See fig. 7	inent per leg	I _{FSM}	10 ms sine or 6 ms rect. pulse rated V _{RRM} applied		1700		
Non-repetitive avalanch	he energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 13 A, L = 0.2 mH		15	mJ	
Repetitive avalanche cu	urrent per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А	



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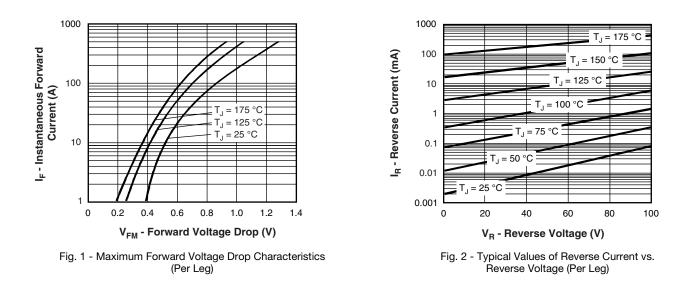
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	100 A	T _{.1} = 25 °C	0.86	V
Maximum forward voltage drop per leg		200 A	1j=25 0	1.03	
See fig. 1		100 A	T 405.00	0.70	
		200 A	T _J = 125 °C	0.84	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3	mA
See fig. 2		T _J = 125 °C	VR - naleu VR	40	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		0.50	V
Forward slope resistance	r _t			1.08	mΩ
Maximum junction capacitance per leg	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		2650	pF
Typical series inductance per leg	L _S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage tempe	Maximum junction and storage temperature range		-55	-	175	°C
Thermal resistance, junction to case	per leg	P	-	-	0.38	°C/W
memairesistance, junction to case	per module	R _{thJC}	-	-	0.19	
Thermal resistance, case to heatsink	Thermal resistance, case to heatsink		-	0.10	-	
Weight			-	68		g
				2.4		oz.
Mounting torque			35.4 (4)	-	53.1 (6)	
Mounting torque center hole			30 (3.4)	-	40 (4.6)	lbf ⋅ in (N ⋅ m)
Terminal torque			30 (3.4)	-	44.2 (5)	()
Vertical pull			-	-	80	- lbf ⋅ in
2" lever pull			-	-	35	חויוטו



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VS-203CNQ100PbF

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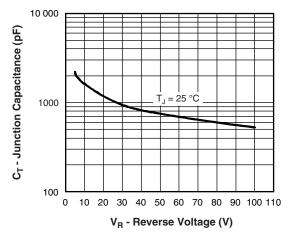


Fig. 3 - Typical Junction Capacitance vs.Reverse Voltage (Per Leg)

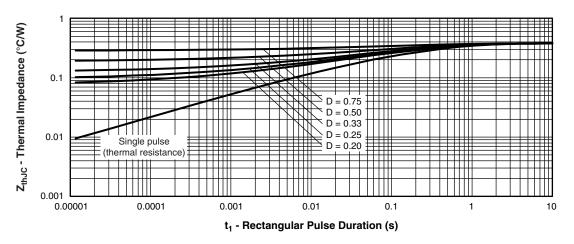


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

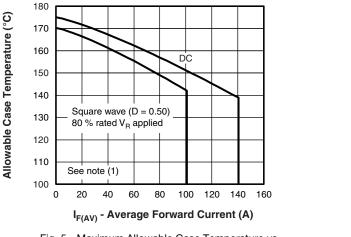


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

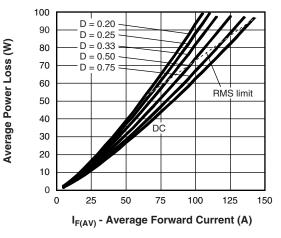


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

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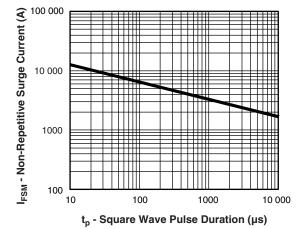


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

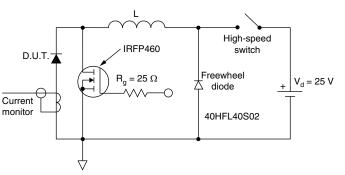
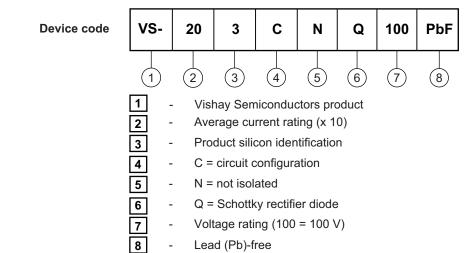


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

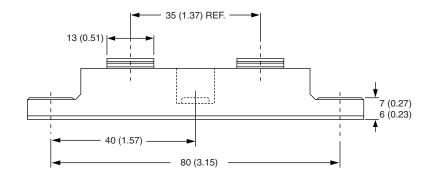


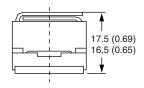


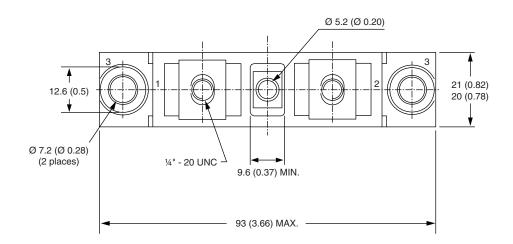
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TO-244

DIMENSIONS in millimeters (inches)









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